

Standard Recovery Diodes, (Hockey PUK Version), 700 A



B-PUK (DO-200AB)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	700 A				
Package	B-PUK (DO-200AB)				
Circuit configuration	Single				

FEATURES

- Wide current range
- High voltage ratings up to 4500 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style B-PUK (DO-200AB)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- · High power drives
- Auxiliary system supplies for traction applications

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		700	A		
I _{F(AV)}	T _{hs}	55	°C		
I _{F(RMS)}		1310	A		
	T _{hs}	25	°C		
1	50 Hz	7500	^		
IFSM	60 Hz	7850	A		
l²t	50 Hz	281	kA ² s		
	60 Hz	257	KA-S		
V _{RRM}	Range	3000 to 4500	V		
TJ		-40 to +150	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE VRRM, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ \text{AT } T_J = T_J \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$		
	30	3000	3100			
VS-SD700CL 36		3600	3700	50		
VS-SD/00CL	40	4000	4100	50		
	45	4600	4600			



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current	1	180° conduction, half sine wave		700 (345)	Α	
at heatsink temperature	I _{F(AV)}	Double side (s	Double side (single side) cooled			°C
Maximum RMS forward current	I _{F(RMS)}	25 °C heatsinl	k temperature do	ouble side cooled	1310	
		t = 10 ms	No voltage		7500	A kA ² s
Maximum peak, one-cycle forward,	l=a	t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	7850	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		6310	
		t = 8.3 ms	reapplied		6600	
	l ² t	t = 10 ms	No voltage		281	
Maximum I ² t for fusing		t = 8.3 ms	reapplied		257	
Maximum 1-t for fusing		t = 10 ms	100 % V _{RRM} reapplied		199	
		t = 8.3 ms			182	
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied			2810	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum			0.88	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.99	\ \ \
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.78	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 0.			0.73	11152
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sinusoidal wave}$ 1.66			1.66	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBO L	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	TJ		-40 to +150	°C
Maximum storage temperature range	T _{Stg}		-55 to +200	
Maximum thermal resistance,	D	DC operation single side cooled	0.11	K/W
junction to heatsink R _{thJ-hs}		DC operation double side cooled	0.05	
Mounting force, ± 10 %			9800 (1000)	N (kg)
Approximate weight			250	g
Case style		See dimensions - link at the end of datasheet	B-PUK (DO	-200AB)

△R _{thJ-hs} CONDUCTION						
CONDUCTION ANGLE SINUSOIDAL CONDUCTION		CONDUCTION	RECTANGULAR	R CONDUCTION	TEST CONDITIONS	UNITS
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS
180°	0.011	0.011	0.008	0.008		
120°	0.014	0.015	0.014	0.014	$T_J = T_J$ maximum	
90°	0.018	0.018	0.019	0.019		K/W
60°	0.026	0.026	0.027	0.028		
30°	0.045	0.046	0.046	0.046		

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

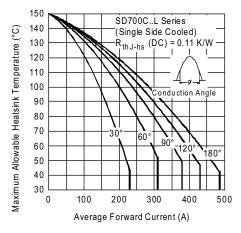


Fig. 1 - Current Ratings Characteristics

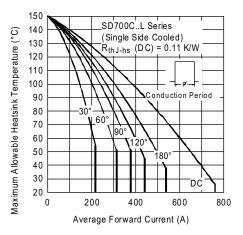


Fig. 2 - Current Ratings Characteristics

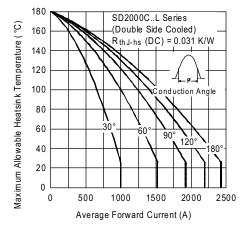


Fig. 3 - Current Ratings Characteristics

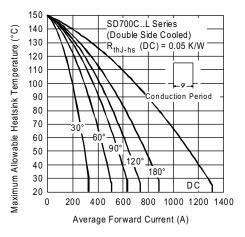


Fig. 4 - Current Ratings Characteristics

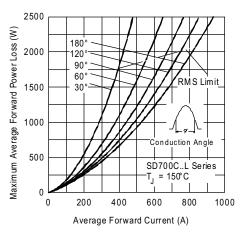


Fig. 5 - Forward Power Loss Characteristics

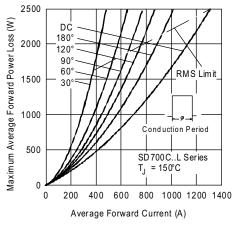


Fig. 6 - Forward Power Loss Characteristics

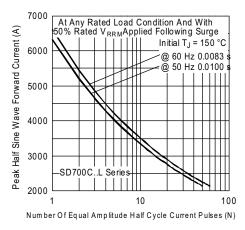


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

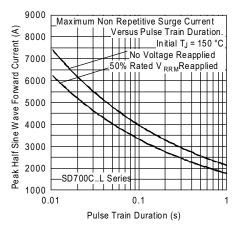


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

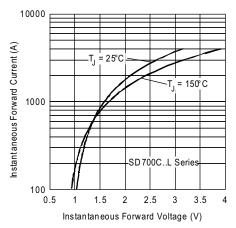


Fig. 9 - Forward Voltage Drop Characteristics

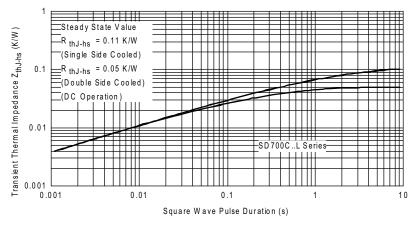
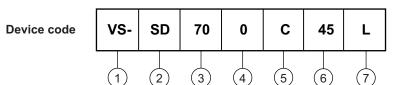


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics



ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Diode

3 - Essential part number

- 0 = standard recovery

C = ceramic PUK

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

- L = PUK case B-PUK (DO-200AB)

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95246			



B-PUK (DO-200AB)

DIMENSIONS in millimeters (inches)

3.5 (0.14) DIA. NOM. x
1.8 (0.07) deep MIN. both ends

VAW. YIO (08.7) (1.08) (0.03) both ends

2 places

C

Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)

53 (2.09) DIA. MAX.

Note: A = Anode

C = Cathode



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